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FDMA3023PZ

July 2014

Dual P-Channel PowerTrench® MOSFET -30 V, -2.9 A, 90 m Ω

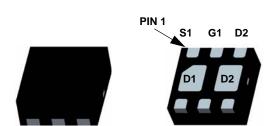
Features

- Max $r_{DS(on)}$ = 90 m Ω at V_{GS} = -4.5 V, I_D = -2.9 A
- Max $r_{DS(on)}$ = 130 m Ω at V_{GS} = -2.5 V, I_D = -2.6 A
- Max $r_{DS(on)} = 170 \text{ m}\Omega$ at $V_{GS} = -1.8 \text{ V}$, $I_D = -1.7 \text{ A}$
- Max $r_{DS(on)} = 240 \text{ m}\Omega$ at $V_{GS} = -1.5 \text{ V}$, $I_D = -1.0 \text{ A}$
- Low profile 0.8 mm maximum in the new package MicroFET 2x2 mm
- HBM ESD protection level > 2 kV (Note 3)
- RoHS Compliant
- Free from halogenated compounds and antimony oxides

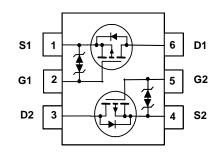
General Description

This device is designed specifically as a single package solution for the battery charge switch in cellular handset and other ultra-portable applications. It features two independent P-Channel MOSFETs with low on-state resistance for minimum conduction losses. When connected in the typical common source configuration, bi-directional current flow is possible.

The MicroFET 2X2 package offers exceptional thermal performance for its physical size and is well suited to linear mode applications.



MicroFET 2x2



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

D1 G2 S2

Symbol	Parameter		Ratings	Units
V_{DS}	Drain to Source Voltage		-30	V
V_{GS}	Gate to Source Voltage		±8	V
	Drain Current -Continuous	(Note 1a)	-2.9	۸
ID	-Pulsed		-6	A
Б	Power Dissipation	(Note 1a)	1.4	W
P_{D}	Power Dissipation	(Note 1b)	0.7	VV
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance for Single Operation, Junction to Ambient	(Note 1a)	86	
$R_{\theta JA}$	Thermal Resistance for Single Operation, Junction to Ambient	(Note 1b)	173	°C/W
$R_{\theta JA}$	Thermal Resistance for Dual Operation, Junction to Ambient	(Note 1c)	69	· C/vv
$R_{\theta JA}$	Thermal Resistance for Dual Operation, Junction to Ambient	(Note 1d)	151	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
323	FDMA3023PZ	MicroFET 2X2	7 "	8 mm	3000 units

Electrical Characteristics $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = -250 \mu A, V_{GS} = 0 V$	-30			V
$\frac{\Delta BV_{DS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25 °C		-24		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -24 V, V _{GS} = 0 V			-1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \mu A$	-0.4	-0.6	-1.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25 °C		3		mV/°C
	$V_{GS} = -4.5 \text{ V}, I_D = -2.9 \text{ A}$		71	90		
		$V_{GS} = -2.5 \text{ V}, I_D = -2.6 \text{ A}$		97	130	
r _{DS(on)}	r _{DS(on)} Static Drain to Source On Resistance	$V_{GS} = -1.8 \text{ V}, I_D = -1.7 \text{ A}$		122	170	mΩ
		$V_{GS} = -1.5 \text{ V}, I_D = -1.0 \text{ A}$		151	240	
		$V_{GS} = -4.5 \text{ V}, I_D = -2.9 \text{ A}, T_J = 125 \text{ °C}$		110	140	
9 _{FS}	Forward Transconductance	$V_{DS} = -5 \text{ V}, I_{D} = -2.9 \text{ A}$		10		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V 45 V V 0 V	400	530	pF
C _{oss}	Output Capacitance	V _{DS} = -15 V, V _{GS} = 0 V, f = 1 MHz	55	70	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1 1/11/12	45	65	pF

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		5	10	ns
t _r	Rise Time	V _{DD} = -15 V, I _D = -1.0 A,	4	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = -4.5 \text{ V}, R_{GEN} = 6 \Omega$	62	100	ns
t _f	Fall Time		18	33	ns
$Q_{g(TOT)}$	Total Gate Charge	45.771 000	7.9	11	nC
Q_{gs}	Gate to Source Charge $V_{DD} = -15 \text{ V}, I_{D} = -2.9 \text{ A}$ $V_{GS} = -4.5 \text{ V}$		0.9		nC
Q_{gd}	Gate to Drain "Miller" Charge	VGS - 4.5 V	1.9		nC

Drain-Source Diode Characteristics

I _S	Maximum Continuous Drain-Source Diode Forward Current				-1.1	Α
V_{SD}	Source to Drain Diode Forward Voltage	d Voltage $V_{GS} = 0 \text{ V}, I_S = -1.1 \text{ A}$ (Note 2)		-0.8	-1.2	V
t _{rr}	Reverse Recovery Time	I _E = -2.9 A, di/dt = 100 A/μs		18	33	ns
Q _{rr}	Reverse Recovery Charge	1F = -2.9 A, αι/αι = 100 A/μS		6.6	13	nC

Notes:

- 1. $R_{\theta JA}$ is determined with the device mounted on a 1 in² oz. copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design.

 (a) $R_{\theta JA} = 86$ °C/W when mounted on a 1 in² pad of 2 oz copper, 1.5 " x 1.5 " x 0.062 " thick PCB. For single operation.

 - (b) $R_{\theta JA}$ = 173 °C/W when mounted on a minimum pad of 2 oz copper. For single operation.
 - (c) $R_{\theta JA} = 69$ °C/W when mounted on a 1 in² pad of 2 oz copper, 1.5 " x 1.5 " x 0.062" thick PCB. For dual operation.
 - (d) $R_{\theta JA}$ = 151 °C/W when mounted on a minimum pad of 2 oz copper. For dual operation.



a)86 °C/W when mounted on a 1 in² pad of 2 oz copper.



b)173 °C/W when mounted on a minimum pad of 2 oz copper.



c)69 °C/W when mounted on a 1 in² pad of 2 oz copper.



d)151 °C/W when mounted on a minimum pad of 2 oz copper.

- 2. Pulse Test : Pulse Width < 300 us, Duty Cycle < 2.0%
- 3. The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

Typical Characteristics T_J = 25 °C unless otherwise noted

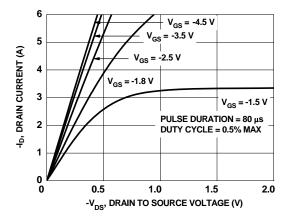


Figure 1. On Region Characteristics

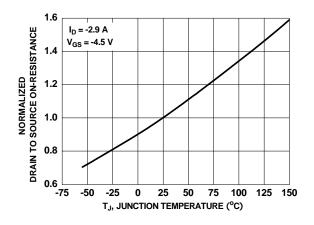


Figure 3. Normalized On Resistance vs Junction Temperature

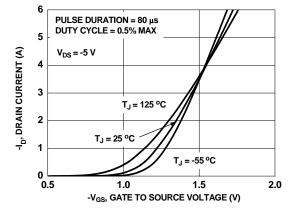


Figure 5. Transfer Characteristics

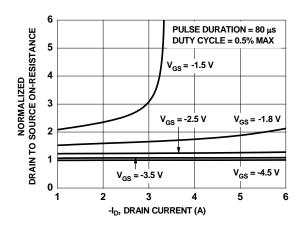


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

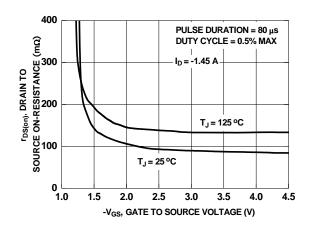


Figure 4. On-Resistance vs Gate to Source Voltage

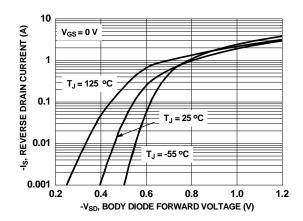


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25$ °C unless otherwise noted

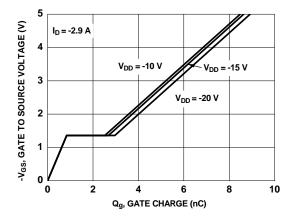
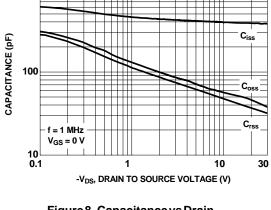


Figure 7. Gate Charge Characteristics



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Figure 8. Capacitance vs Drain to Source Voltage

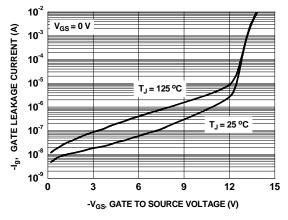


Figure 9. Gate Leakage vs Gate to Source Voltage

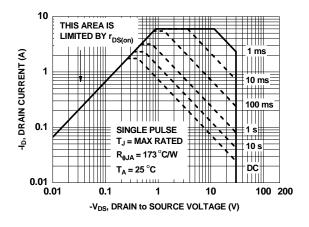


Figure 10. Forward Bias Safe Operating Area

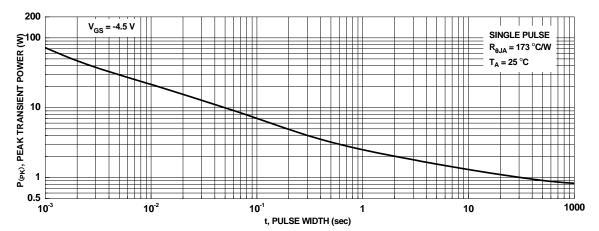


Figure 11. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25$ °C unless otherwise noted

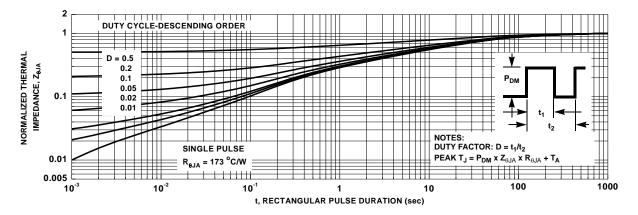
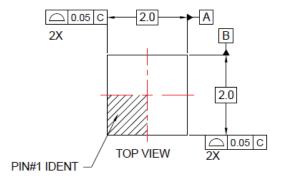
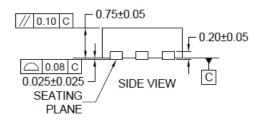
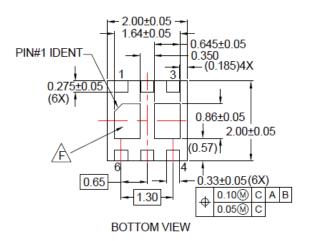


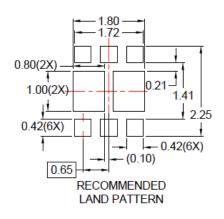
Figure 12. Junction-to-Ambient Transient Thermal Response Curve

Dimensional Outline and Pad Layout









NOTES:

- A. CONFORM TO JADEC REGISTRATIONS MO-229, VARIATION VCCC, EXCEPT WHERE NOTED.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
- E. DRAWING FILENAME: MKT-UMLP16Erev4
- F. NON-JEDEC DUAL DAP



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